SWITCHMODE™ Power Rectifier 80 V, 30 A

Features and Benefits

- Low Power Loss/High Efficiency
- High Surge Capacity
- 30 A Total (15 A Per Diode Leg)
- These are Pb-Free Devices

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model = 3B

Machine Model = C

MAXIMUM RATINGS

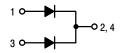
Please See the Table on the Following Page



ON Semiconductor®

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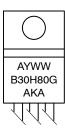
SCHOTTKY BARRIER RECTIFIER 30 AMPERES 80 VOLTS

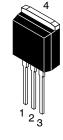




MARKING DIAGRAM

TO-220AB CASE 221A PLASTIC





I²PAK (TO-262) CASE 418D PLASTIC STYLE 3



A = Assembly Location

Y = Year
WW = Work Week
B30H80 = Device Code
G = Pb-Free Package
AKA = Polarity Designator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	80	V	
Average Rectified Forward Current (T _C = 130°C) Per Diode Per Device	I _{F(AV)}	15 30	А	
Peak Repetitive Forward Current (Square Wave, 20 kHz, T _C = 130°C)	I _{FM}	30	А	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	240	Α	
Storage Temperature	T _{stg}	-65 to +175	°C	
Operating Junction Temperature (Note 1)	T _J	-20 to +150	°C	
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance			°C/W
- Junction-to-Case	$R_{ heta JC}$	2.0	
Junction-to-Ambient	$R_{ hetaJA}$	70	

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	Min	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 2)	VF				V
$(i_F = 3 \text{ A}, T_J = 25^{\circ}\text{C})$		-	0.49	0.58	
$(i_F = 3 \text{ A}, T_J = 25^{\circ}\text{C})$		_	0.37	0.45	
$(i_F = 15 \text{ A}, T_J = 25^{\circ}\text{C})$		_	0.65	0.78	
(i _F = 15 A, T _J = 125°C)		_	0.55	0.65	
$(i_F = 30 \text{ A}, T_J = 25^{\circ}\text{C})$		_	0.77	0.88	
$(i_F = 30 \text{ A}, T_J = 125^{\circ}\text{C})$		-	0.67	0.75	
Maximum Instantaneous Reverse Current (Note 2)	İR				mA
(Rated DC Voltage, T _J = 125°C)		_	12	35	
(Rated DC Voltage, T _J = 25°C)		-	0.017	0.250	

^{2.} Pulse Test: Pulse Width = 300 $\mu s, \, Duty \, Cycle \leq 2.0\%.$

DEVICE ORDERING INFORMATION

Device Order Number	Package Type	Shipping [†]
MBR30H80CTG	TO-220 (Pb-Free)	50 Units / Rail
MBRB30H80CT-1G	I ² PAK (Pb-Free)	50 Units / Rail

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

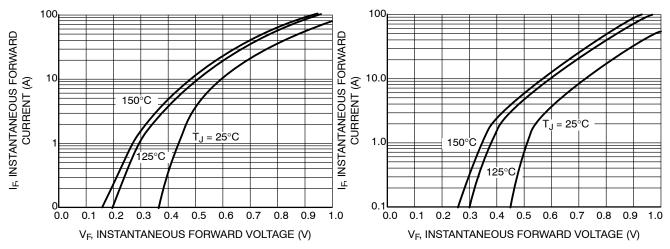


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

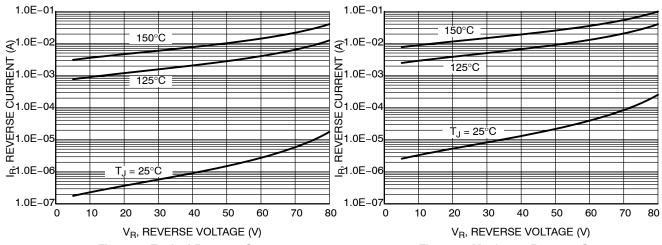
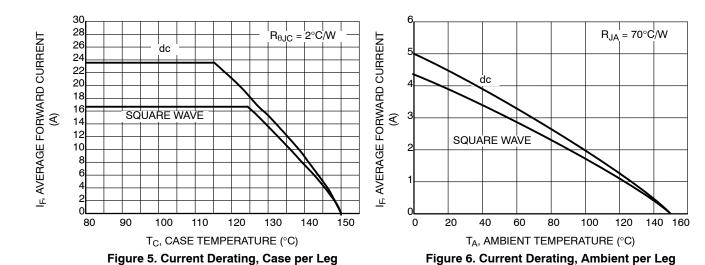
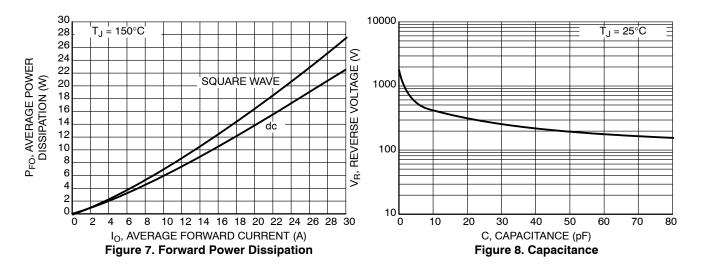


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current



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100 R(t), TRANSIENT THERMAL RESISTANCE D = 0.5 10 0.05 0.01 **→** t₁ **←** 0.1 SINGLE PULSE DUTY CYCLE, $D = t_1/t_2$ 0.01 0.000001 0.00001 0.0001 0.001 0.01 0.1 1000 10 100 t₁, TIME (sec)

Figure 9. Thermal Response Junction-to-Ambient

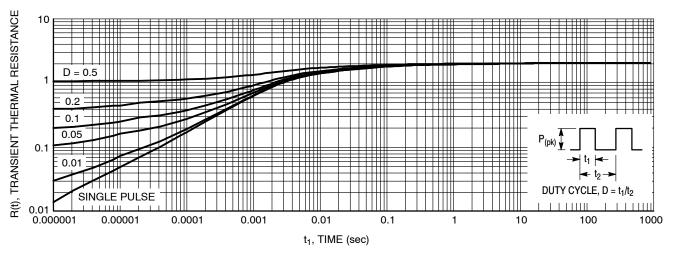
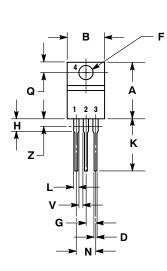
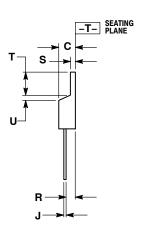


Figure 10. Thermal Response Junction-to-Case

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





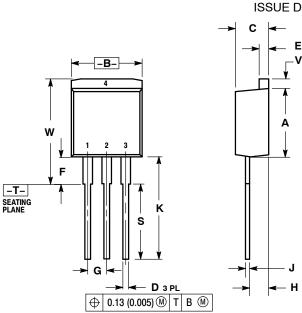
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
7	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
ø	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
5	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6:
 PIN 1. ANODE
 2. CATHODE
 3. ANODE
 4. CATHODE

PACKAGE DIMENSIONS

I²PAK (TO-262) CASE 418D-01



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.335	0.380	8.51	9.65	
В	0.380	0.406	9.65	10.31	
С	0.160	0.185	4.06	4.70	
D	0.026	0.035	0.66	0.89	
E	0.045	0.055	1.14	1.40	
F	0.122 REF		3.10 REF		
G	0.100 BSC		2.54	2.54 BSC	
Н	0.094	0.110	2.39	2.79	
J	0.013	0.025	0.33	0.64	
K	0.500	0.562	12.70	14.27	
S	0.390 REF		9.90	9.90 REF	
٧	0.045	0.070	1.14	1.78	
W	0.522	0.551	13.25	14.00	

STYLE 3:

PIN 1. ANODE

- 2. CATHODE
- 3. ANODE 4. CATHODE

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